In the Claims

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims

- 1. (Currently amended) A <u>transmissive</u> wire grid polarizer with double metal layers <u>for</u> <u>visible spectrum</u>, comprising:
 - a transparent substrate;
 - an array of parallel and elongated dielectric protrusions formed on the transparent substrate, wherein the dielectric protrusions have a period and a trench is located between adjacent dielectric protrusions;
 - a first metal layer having a first thickness formed in the trench; and
 - a second metal layer having a second thickness and a width formed on each dielectric protrusion, wherein the first and second metal layers are separated by a vertical distance;

wherein the period is not greater than 250nm;

wherein the first thickness is not greater than 150nm and is equal to the second thickness; wherein the vertical distance is not greater than 100nm;

wherein the ratio of the width to the period is in a range of 25~75%.

2. (original) The wire grid polarizer according to claim 1, wherein the transparent substrate is exposed in the trench.

- 3. (original) The wire grid polarizer according to claim 1, wherein a remaining dielectric layer is formed on a bottom of the trench.
- 4. (previously presented) The wire grid polarizer according to claim 1, wherein a thickness of the transparent substrate is 500~1500 μm.
- 5. (original) The wire grid polarizer according to claim 4, wherein the transparent substrate is a glass or plastic substrate.
- 6. (original) The wire grid polarizer according to claim 1, wherein the dielectric layers are PMMA (polymethyl methacrylate) layers.
- 7. (original) The wire grid polarizer according to claim 1, wherein the first metal layer is an Au, Ag, Cu or Al layer.
- 8. (original) The wire grid polarizer according to claim 1, wherein the second metal layer is an Au, Ag, Cu or Al layer.
- 9. (original) The wire grid polarizer according to claim 1, wherein the first and second metal layers comprise the same material.
 - 10. (original) The wire grid polarizer according to claim 1, further comprising: a protective layer formed on the first and second metal layers.

- 11. (original) The wire grid polarizer according to claim 10, wherein the protective layer is a SiO₂, SiN or SiON layer.
- 12. (original) The wire grid polarizer according to claim 1, wherein the period is in a range of 10~250nm.
- 13. (original) The wire grid polarizer according to claim I, wherein the first or second thickness is in a range of 30~150nm.
- 14. (original) The wire grid polarizer according to claim 1, wherein the vertical distance is in a range of 10~100nm.
- 15. (Currently amended) A <u>transmissive</u> wire grid polarizer with double metal layers <u>for visible spectrum</u>, comprising:
 - a transparent substrate;
 - an array of parallel and elongated dielectric protrusions formed on the transparent substrate, wherein the dielectric protrusions have a period and a trench is located between adjacent dielectric protrusions;
 - a first metal layer having a first thickness formed in the trench; and
 - a second metal layer having a second thickness and a width formed on each of the dielectric protrusions, wherein a vertical distance is between the first and second metal layers;

wherein the period is in a range of 10~250nm;

wherein the first thickness is in a range of 30-150nm and is equal to the second thickness;

wherein the vertical distance is in a range of 10-100nm;

wherein the ratio of the width to the period is in a range of 25-75%.

- 16. (original) The wire grid polarizer according to claim 15, wherein the transparent substrate is exposed in the trench.
- 17. (original) The wire grid polarizer according to claim 15, wherein a remaining dielectric layer is formed on a bottom of the trench.
- 18. (Currently amended) A method of forming a <u>transmissive</u> wire grid polarizer with double metal layers for visible spectrum, comprising the steps of:

providing a transparent substrate;

forming an array of parallel and elongated dielectric protrusions on the transparent substrate, wherein the dielectric protrusions have a period and a trench is located between adjacent dielectric protrusions;

forming a first metal layer having a first thickness in the trench; and

forming a second metal layer having a second thickness and a width on each dielectric protrusion, wherein the first and second metal layers are separated by a vertical distance;

wherein the period is in a range of 10~250nm;

wherein the first thickness is in a range of 30~150nm and is equal to the second thickness;

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wherein the vertical distance is in a range of 10~100nm; wherein the ratio of the width to the period is in a range of 25~75%.

- 19. (original) The method according to claim 18, the transparent substrate is exposed in the trench.
- 20. (original) The method according to claim 18, wherein a remaining dielectric layer is formed on a bottom of the trench.
 - 21. (original) The method according to claim 18, further comprising the step of: forming a protective layer on the first and second metal layers.
- 22. (original) The method according to claim 18, wherein the dielectric layers are formed by photolithography or nanoimprint.